Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.185 inches and 0.205 inches

Terminal Length:

1.100 inches

Overall Diameter:

Between 0.100 inches and 0.107 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

450.0 nonrepetitive peak reverse voltage, peak total value and 400.0 working peak reverse voltage, peak total value

Current Rating Per Characteristic:

1.00 amperes forward current, total rms megahertz

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Test Data Document:

80009-152-0400-00 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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